MPSW01, MPSW01A

One Watt High Current Transistors

NPN Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage MPSW01 MPSW01A	V _{CEO}	30 40	Vdc
Collector - Base Voltage MPSW01 MPSW01A	V _{CBO}	40 50	Vdc
Emitter - Base Voltage	V _{EBO}	5.0	Vdc
Collector Current - Continuous	I _C	1000	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.0 8.0	W mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	2.5 20	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

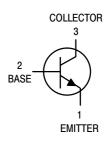
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

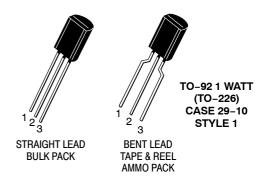
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



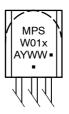
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MARKING DIAGRAM



x = 01A Devices

A = Assembly Location

/ = Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MPSW01, MPSW01A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

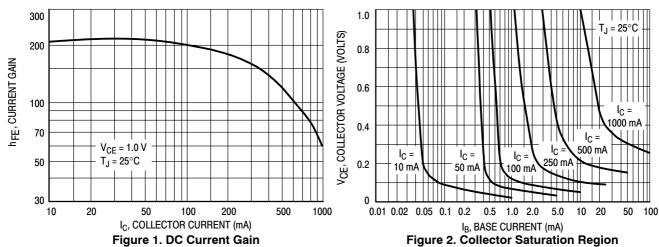
Characteristic	Symbol	Min	Max	Unit				
OFF CHARACTERISTICS								
Collector – Emitter Breakdown Voltage (Note 1) (I_C = 10 mAdc, I_B = 0)	MPSW01 MPSW01A	V _{(BR)CEO}	30 40	_ _	Vdc			
Collector – Base Breakdown Voltage (I_C = 100 μ Adc, I_E = 0)	MPSW01 MPSW01A	V _(BR) CBO	40 50	- -	Vdc			
Emitter – Base Breakdown Voltage ($I_E = 100 \mu Adc, I_C = 0$)		V _{(BR)EBO}	5.0	-	Vdc			
Collector Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	MPSW01 MPSW01A	I _{CBO}	- -	0.1 0.1	μAdc			
Emitter Cutoff Current (V _{EB} = 3.0 Vdc, I _C = 0)		I _{EBO}	-	0.1	μAdc			
ON CHARACTERISTICS (Note 1)								
DC Current Gain		h _{FE}	55 60 50	- - -	-			
Collector – Emitter Saturation Voltage ($I_C = 1000 \text{ mAdc}$, $I_B = 100 \text{ mAdc}$	c)	V _{CE(sat)}	-	0.5	Vdc			
Base-Emitter On Voltage (I _C = 1000 mAdc, V _{CE} = 1.0 Vdc)		V _{BE(on)}	-	1.2	Vdc			
SMALL-SIGNAL CHARACTERISTICS								
Current – Gain — Bandwidth Product (I_C = 50 mAdc, V_{CE} = 10 Vdc, f	= 20 MHz)	f _T	50	-	MHz			
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	_	20	pF			

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

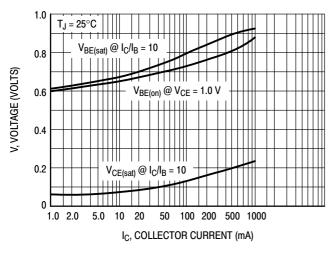
ORDERING INFORMATION

Device	Package	Shipping [†]
MPSW01	TO-92	5000 Units / Bulk
MPSW01G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSW01AG	TO-92 (Pb-Free)	5000 Units / Bulk
MPSW01ARLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSW01ARLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



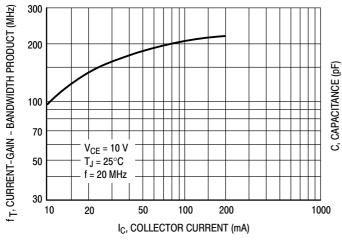
MPSW01, MPSW01A



O -0.8

Figure 3. "ON" Voltages

Figure 4. Temperature Coefficient



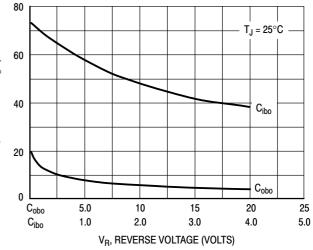


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

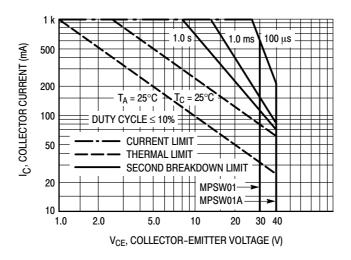
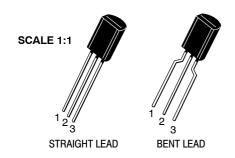


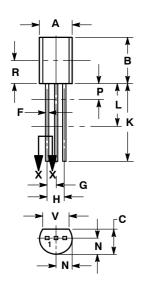
Figure 7. Active Region — Safe Operating Area





TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE A**

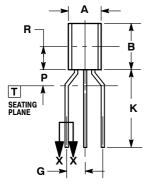
DATE 08 MAY 2012

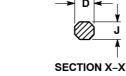


STRAIGHT LEAD



BENT LEAD





NOTES:

- TES:
 DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS
 UNCONTROLLED.
 DIMENSION F APPLIES BETWEEN DIMENSIONS P
 AND L DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD
 DIMENSIONS ARE UNCONTROLLED IN DIMENSION
 P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	-	12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135	-	3.43	
٧	0.135		3.43	

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: INCHES.

 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS

- UNCONTROLLED.

 DIMENSION F APPLIES BETWEEN DIMENSIONS P
 AND L. DIMENSIONS D AND J APPLY BETWEEN
 DIMENSIONS LAND K MINIMUM. THE LEAD
 DIMENSIONS ARE UNCONTROLLED IN DIMENSION
 P AND BEYOND DIMENSION K MINIMUM.

		INC	HES	MILLIN	IETERS
DII	M	MIN	MAX	MIN	MAX
Α		0.175	0.205	4.44	5.21
В		0.290	0.310	7.37	7.87
C	;	0.125	0.165	3.18	4.19
D)	0.018	0.021	0.46	0.53
G	i	0.094	0.102	2.40	2.80
J		0.018	0.024	0.46	0.61
K		0.500		12.70	
N		0.080	0.105	2.04	2.66
P			0.100		2.54
R	1	0.135		3.43	
٧	_	0.135		3.43	

STYLES ON PAGE 2

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TO-92 (TO-226) 1 WATT CASE 29-10

ISSUE A

DATE 08 MAY 2012

STYLE 1: PIN 1. 2. 3.	EMITTER BASE	PIN 1. 2.	BASE EMITTER	STYLE 3: PIN 1. 2. 3.	ANODE ANODE	PIN 1.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN
STYLE 6: PIN 1. 2. 3.	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	STYLE 9: PIN 1. 2. 3.	BASE 1 EMITTER BASE 2		CATHODE
2.	ANODE	STYLE 12: PIN 1. 2. 3.	MAIN TERMINAL 1	PIN 1.	ANODE 1 GATE CATHODE 2	PIN 1.	EMITTER	PIN 1. 2.	ANODE 1
PIN 1. 2.	ANODE GATE	PIN 1. 2.	BASE	PIN 1. 2.	ANODE	2.	GATE ANODE CATHODE	2.	NOT CONNECTED
PIN 1. 2.	COLLECTOR EMITTER	STYLE 22: PIN 1. 2. 3.	SOURCE GATE DRAIN	PIN 1. 2.	GATE SOURCE DRAIN	PIN 1. 2.	EMITTER COLLECTOR/ANODE CATHODE	PIN 1. 2.	MT 1 GATE MT 2
	V _{CC}	PIN 1. 2.		PIN 1. 2.	CATHODE ANODE GATE	PIN 1. 2.	NOT CONNECTED ANODE CATHODE	PIN 1. 2.	DRAIN GATE SOURCE
	GATE DRAIN SOURCE	PIN 1. 2.	BASE	STYLE 33: PIN 1. 2. 3.	RETURN INPUT	PIN 1. 2.			

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PAGE 3 OF 3

ISSUE	REVISION	DATE
0	ADDED BENT-LEAD TAPE & REEL VERSION. TRANSFERRED FROM OLD 98A# 98ASB42022B TO NEW 98AON52857E. REQ. BY D. TRUHITTE.	17 AUG 2010
Α	REMOVED REFERENCE TO BULK PACK, AMMO PACK & TAPE & REEL. REQ. BY M. JONES.	08 MAY 2012

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